

Ultrafast Nonlinear Signal Processing in Silicon Waveguides (invited paper)

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Abstract: We describe recent demonstrations of exploiting highly nonlinear silicon waveguides for ultrafast optical signal processing. We describe wavelength conversion and serial-to-parallel conversion of 640 Gbit/s data signals and 1.28 Tbit/s demultiplexing and all-optical sampling.

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1. Introduction

From a power consumption perspective, all-optical signal processing may be suitable for functionalities where many bits are processed in a few devices [1]. This is the case for e.g. wavelength conversion and all-optical regeneration, especially if very high channel bit rates are considered. Furthermore, if the optical signal processing can be achieved in CMOS-compatible silicon waveguides, then ultra-fast, energy-efficient photonic chips may become a reality for simple processing applications, which may be interesting for future ultra-fast serial data links, e.g. in data centres, between servers, in super-computers or even for niche applications in the core transport network..

In this paper we review some promising all-optical functionalities based on silicon photonics. In particular we use nano-engineered silicon waveguides enabling efficient phase-matched four-wave mixing (FWM) for ultra-high-speed optical signal processing of ultra-high bit rate serial data signals. We show that silicon can indeed be used to control Tbit/s serial data signals [2], perhaps paving the way for future ultra-fast optical chips. From an energy perspective, the most promising functionalities are those that process many bits in few devices, e.g.. *conversion-type* functionalities where e.g. a full serial data signal is converted to some other format. In such a scheme, all the bits in the serial signal are processed in the same device. We will describe various potentially energy-efficient schemes of conversion, focusing on wavelength conversion [3] and serial-to-parallel conversion [4], all using Si waveguides.

2. Silicon photonics for optical signal processing – background

Nonlinear signal processing in silicon by the nonlinear optical Kerr effect has been described and used for many applications over the last 5-10 years, e.g. NRZ-to-RZ conversion [5], regeneration, multi-casting, multiple-wavelength source, monitoring, demultiplexing and many more, see e.g. [6-25]. Most of these demonstrations rely on ultrafast FWM or even two-photon absorption (TPA). Adding other nonlinear materials to Si slot waveguides can induce a high nonlinearity but avoid the detrimental nonlinear absorption of silicon. Such materials could be organic molecules [26-27], recently used to enable a 40 Gbit/s data modulator [28] and demultiplexing 170 Gbit/s [29].

3. Ultra-fast optical signal processing: recent demonstrations at DTU Fotonik

In the DTU Fotonik Tbit/s test-bed, an up-to 1.28 Tbit/s data signal is generated by optical time division multiplexing (OTDM) of a 10 Gbit/s base rate data signal based on very short optical pulses (300 fs FWHM), see principle sketch in Fig. 1 (left). The pulses are data modulated (amplitude or phase) and multiplexed in a fibre delay line multiplexer up to 1.28 Tbit/s. This signal may then be used to test a variety of components and functionalities, including transmission [30] and as described here signal processing using silicon. Fig. 1 shows the basic principle of multiplexing from low rate data streams, e.g. 10 Gbit/s, to e.g. 1.28 Tbit/s. An eye diagram of the generated 1.28 Tbit/s, as measured with a commercial ultrafast optical sampling oscilloscope, is shown in Fig. 1 (middle). Fig. 1(right) shows the same signal measured with a silicon sampling systems, revealing superior timing resolution [2].

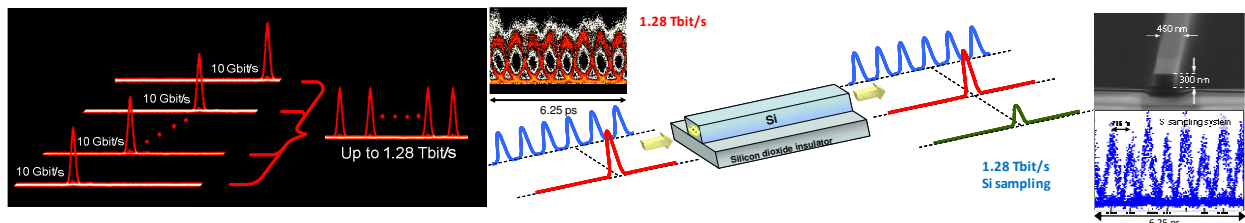


Figure 1. Tbit/s signal generation and principle of four-wave mixing optical signal processing in a silicon waveguide. Right: Image of typical waveguide structure and a sampled eye diagram of a 1.28 Tbit/s data signal using the Si waveguide [2].

Fig. 1 (right) shows an image of the used nanowire [31], which has tapered end-sections providing low coupling loss (1.5 dB per facet). Fig. 1 (middle) shows the principle of pulsed FWM. When a control pulse co-propagates with a data pulse, an idler copy is generated at the pump pulse rate. We have shown that we can process Tbit/s data signals using FWM in an all-Si nanowire, by demonstrating demultiplexing and optical sampling of a 1.28 Tbit/s data signal [2], and moreover, recently shown that the processing rate can be increased to 320 and 640 GHz, when we did 320 and 640 Gbit/s wavelength conversion [3][10], see Fig. 2 below. Fig. 2 shows 640 Gbit/s DPSK wavelength conversion results together with BER measurements for 320 Gbit/s. This is the highest signal processing speed reported using silicon, and figure 2 shows full BER characterization for all tributary channels. All channels are within the standard FEC requirements with a 7% overhead, corresponding to 595 Gbit/s error-free conversion. This functionality is promising for low energy consumption: we used as low as 110 fJ/bit pump energy for the 640 Gbit/s case. We have previously shown 95 fJ/bit for 640 Gbit/s wavelength conversion using highly nonlinear fiber (HNLF) [31]. Wavelength conversion is more challenging than demultiplexing, as all time channels need to be switched simultaneously, whereas a demultiplexer only switches one channel at a time. It is still not well established which effect the free carriers generated through two-photon absorption have on the FWM processing speed, so the demonstration of ultra-high-speed wavelength conversion indicates that it may be possible to isolate the FWM effect from the TPA/FCA effects and allow for ultra-fast processing. Here this was done simply by keeping the CW pump power below the TPA threshold. Note that the BER limitations in the 640 Gbit/s wavelength conversion result is due to OSNR limitations, stemming from the relatively poor conversion efficiency (-30 dB) of the used device and the insertion loss, resulting in a very modest FWM output power.

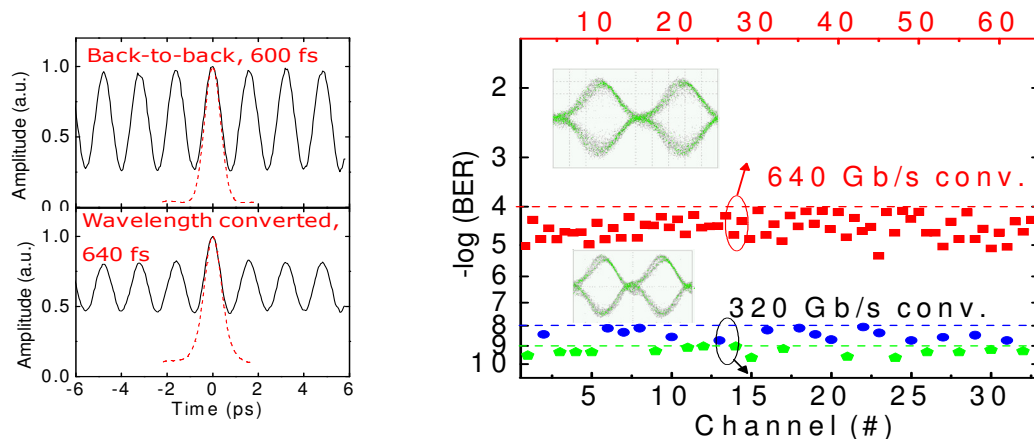


Figure 2. 640 Gbit/s wavelength conversion using FWM in a nonlinear silicon waveguide. Left: autocorrelation traces of the original 640 Gbit/s DPSK signal and the converted 640 Gbit/s DPSK signal. There is a slight pulse broadening owing to limited filters after conversion. Right: BER results for 320 and 640 Gbit/s DPSK wavelength conversion [3] for all data channels. All results are within FEC requirements, as all channels are below BER 10^{-4} .

As mentioned above, 1.28 Tbit/s demultiplexing has been demonstrated [2], but a single-channel demultiplexer may not be the best choice in terms of energy efficiency. If the demultiplexing can be based on a conversion scheme like the wavelength conversion, it may be more efficient [1]. With the development of the time lens concept [32-33], or equivalently the optical Fourier transformation (OFT) technique [34], a versatile new tool for manipulating optical waveforms has been created. It has for instance been used for dispersion compensation [34], timing jitter suppression [33], Ethernet packet synchronization [35], optical pulse shaping of e.g. flat-top pulses [36], and recently also for serial-to-parallel data conversion [37-38]. The technique allows for spectral-to-time domain and time-to-spectral domain transformations. In [4], we showed this could be done in a Si waveguide. The basic principle is sketched in Fig. 3 (left). The OFT is based on FWM in the Si waveguide by chirped pump and data pulses. If the pump is dispersed twice as much as the data, spectral compression of the converted channels is achieved, and each temporal channel is furthermore converted to a separate WDM channel. This is because each OTDM channel overlaps with a different part of the pump spectrum, and will be converted to different idler wavelengths. Balancing the dispersion of the pump and data with the said factor of two gives optimal spectral compression. In [4], 25 GHz spaced DWDM channels were generated this way from a 640 Gbit/s OTDM data signal. Fig. 3 (middle) shows the involved spectra. Note that the pump spectrum is made flat-top in order to also create a flat-top temporal waveform to overlap with more than half of the OTDM channels. Fig. 3 (right) shows the converted WDM channels and their corresponding BER performance. 40 of the 64 OTDM tributaries were simultaneously demultiplexed to individual 25 GHz spaced DWDM channels with BER performance below the FEC

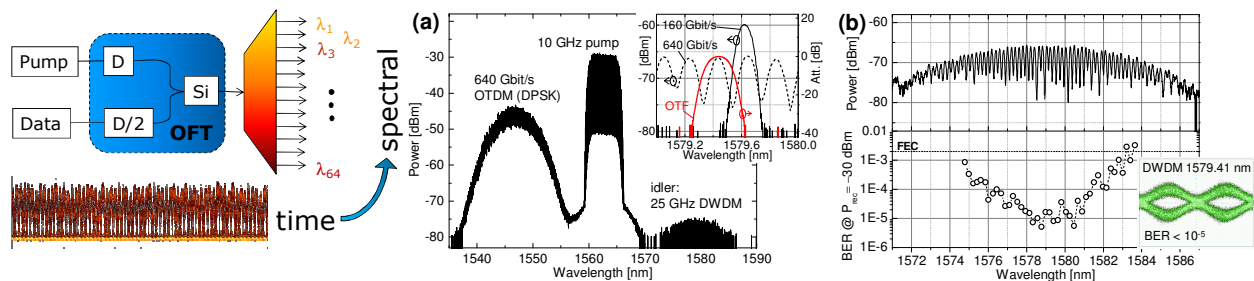


Figure 3. 640 Gbit/s serial-to-parallel conversion in a nonlinear silicon waveguide using the optical time lens or optical Fourier transformation (OFT) technique. Left: schematic setup. Middle (a): involved spectra, of the 640 Gbit/s DPSK data signal, the 10 GHz flat-top pump and the resulting 25 GHz spaced DWDM channels (inset: zoom-in on DWDM channels and optical tunable filter (OTF) transfer function to filter out individual DWDM channels. Right (b): converted DWDM channels and corresponding BER performance. 40 channels are within FEC limits of $2E-3$ BER, i.e. more than half of all the 64 channels are simultaneously demultiplexed [4].

limit. This means that only two OFT units would be needed to demultiplex all channels, instead of 64 individual demultiplexers. This type of conversion may thus prove more energy efficient and more practical.

4. Conclusion

We have described recent advances in the use of silicon nanowires for all-optical signal processing. We have focused on conversion experiments and shown wavelength conversion and serial-to-parallel conversion of 640 Gbit/s data signals.

5. References

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